

SEMiX202GB12Vs



SEMiX[®] 2s

SEMiX202GB12Vs

Features

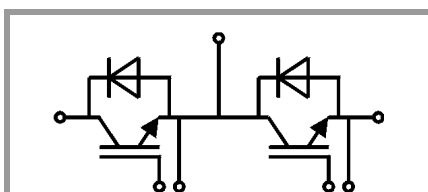
- Homogeneous Si
- $V_{CE(sat)}$ with positive temperature coefficient
- High short circuit capability
- UL recognised file no. E63532

Typical Applications*

- AC inverter drives
- UPS
- Electronic Welding

Remarks

- Case temperature limited to $T_C=125^\circ\text{C}$ max.
- Product reliability results are valid for $T_j=150^\circ\text{C}$
- Dynamic values apply to the following combination of resistors:
 $R_{Gon,main} = 1,5 \Omega$
 $R_{Goff,main} = 1,5 \Omega$
 $R_{G,X} = 2,2 \Omega$
 $R_{E,X} = 0,5 \Omega$



GB

Absolute Maximum Ratings				
Symbol	Conditions	Values	Unit	
IGBT				
V_{CES}		1200	V	
I_C	$T_j = 175^\circ\text{C}$	$T_c = 25^\circ\text{C}$	310	A
		$T_c = 80^\circ\text{C}$	237	A
I_{Cnom}		200	A	
I_{CRM}	$I_{CRM} = 3 \times I_{Cnom}$	600	A	
V_{GES}		-20 ... 20	V	
t_{psc}	$V_{CC} = 600\text{ V}$ $V_{GE} \leq 15\text{ V}$ $V_{CES} \leq 1200\text{ V}$	$T_j = 125^\circ\text{C}$	10	μs
T_j		-40 ... 175	$^\circ\text{C}$	
Inverse diode				
I_F	$T_j = 175^\circ\text{C}$	$T_c = 25^\circ\text{C}$	229	A
		$T_c = 80^\circ\text{C}$	172	A
I_{Fnom}		200	A	
I_{FRM}	$I_{FRM} = 3 \times I_{Fnom}$	600	A	
I_{FSM}	$t_p = 10\text{ ms, sin } 180^\circ, T_j = 25^\circ\text{C}$	990	A	
T_j		-40 ... 175	$^\circ\text{C}$	
Module				
$I_{t(RMS)}$	$T_{terminal} = 80^\circ\text{C}$	600	A	
T_{stg}		-40 ... 125	$^\circ\text{C}$	
V_{isol}	AC sinus 50Hz, $t = 1\text{ min}$	4000	V	

Characteristics					
Symbol	Conditions	min.	typ.	max.	Unit
IGBT					
$V_{CE(sat)}$	$I_C = 200\text{ A}$ $V_{GE} = 15\text{ V}$ chipllevel	$T_j = 25^\circ\text{C}$	1.75	2.2	V
		$T_j = 150^\circ\text{C}$	2.2	2.5	V
V_{CE0}		$T_j = 25^\circ\text{C}$	0.94	1.04	V
		$T_j = 150^\circ\text{C}$	0.88	0.98	V
r_{CE}	$V_{GE} = 15\text{ V}$	$T_j = 25^\circ\text{C}$	4.0	5.8	$\text{m}\Omega$
		$T_j = 150^\circ\text{C}$	6.6	7.6	$\text{m}\Omega$
$V_{GE(th)}$	$V_{GE}=V_{CE}, I_C = 8\text{ mA}$	5.5	6	6.5	V
I_{CES}	$V_{GE} = 0\text{ V}$ $V_{CE} = 1200\text{ V}$	$T_j = 25^\circ\text{C}$	0.1	0.3	mA
		$T_j = 150^\circ\text{C}$			mA
C_{ies}	$V_{CE} = 25\text{ V}$		12.0		nF
C_{oes}	$V_{GE} = 0\text{ V}$		1.18		nF
C_{res}			1.18		nF
Q_G	$V_{GE} = -8\text{ V...} + 15\text{ V}$		2200		nC
R_{Gint}	$T_j = 25^\circ\text{C}$		3.75		Ω
$t_{d(on)}$	$V_{CC} = 600\text{ V}$ $I_C = 200\text{ A}$	$T_j = 150^\circ\text{C}$	424		ns
t_r	$V_{GE} = \pm 15\text{ V}$	$T_j = 150^\circ\text{C}$	64		ns
E_{on}	$R_{Gon} = 2.9\ \Omega$	$T_j = 150^\circ\text{C}$	24.9		mJ
$t_{d(off)}$	$R_{Goff} = 2.9\ \Omega$	$T_j = 150^\circ\text{C}$	619		ns
t_f	$di/dt_{on} = 3800\text{ A}/\mu\text{s}$ $di/dt_{off} = 2000\text{ A}/\mu\text{s}$	$T_j = 150^\circ\text{C}$	90		ns
E_{off}	$du/dt_{off} = 6500\text{ V}/\mu\text{s}$	$T_j = 150^\circ\text{C}$	24.1		mJ
$R_{th(j-c)}$	per IGBT			0.14	K/W

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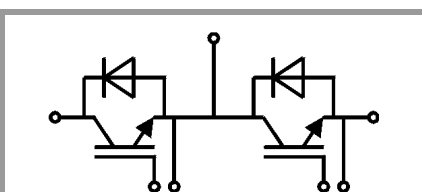
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GB

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
Inverse diode						
$V_F = V_{EC}$	$I_F = 200 \text{ A}$ $V_{GE} = 0 \text{ V}$ chip	$T_j = 25^\circ\text{C}$		2.2	2.52	V
		$T_j = 150^\circ\text{C}$		2.1	2.5	V
V_{F0}		$T_j = 25^\circ\text{C}$	1.1	1.3	1.5	V
		$T_j = 150^\circ\text{C}$	0.7	0.9	1.1	V
r_F		$T_j = 25^\circ\text{C}$	4.0	4.5	5.1	m Ω
		$T_j = 150^\circ\text{C}$	5.3	6.3	6.8	m Ω
I_{RRM}	$I_F = 200 \text{ A}$	$T_j = 150^\circ\text{C}$		212		A
Q_{rr}	$di/dt_{off} = 3900 \text{ A}/\mu\text{s}$	$T_j = 150^\circ\text{C}$		36		μC
E_{rr}	$V_{GE} = -15 \text{ V}$ $V_{CC} = 600 \text{ V}$	$T_j = 150^\circ\text{C}$		14.5		mJ
$R_{th(j-c)}$	per diode				0.26	K/W
Module						
L_{CE}				18		nH
$R_{CC'+EE'}$	res., terminal-chip	$T_C = 25^\circ\text{C}$		0.7		m Ω
		$T_C = 125^\circ\text{C}$		1		m Ω
$R_{th(c-s)}$	per module			0.045		K/W
M_s	to heat sink (M5)		3		5	Nm
M_t		to terminals (M6)	2.5		5	Nm
						Nm
w					250	g
Temperatur Sensor						
R_{100}	$T_C=100^\circ\text{C}$ ($R_{25}=5 \text{ k}\Omega$)			$493 \pm 5\%$		Ω
$B_{100/125}$	$R(T)=R_{100}\exp[B_{100/125}(1/T-1/T_{100})]$; $T[\text{K}]$;			$3550 \pm 2\%$		K

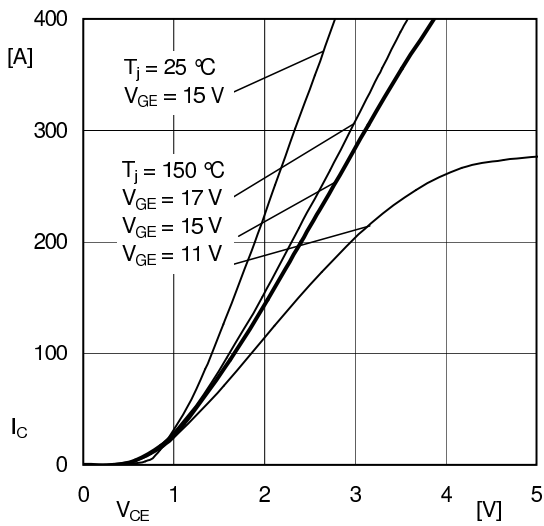


Fig. 1: Typ. output characteristic, inclusive $R_{CC'+EE'}$

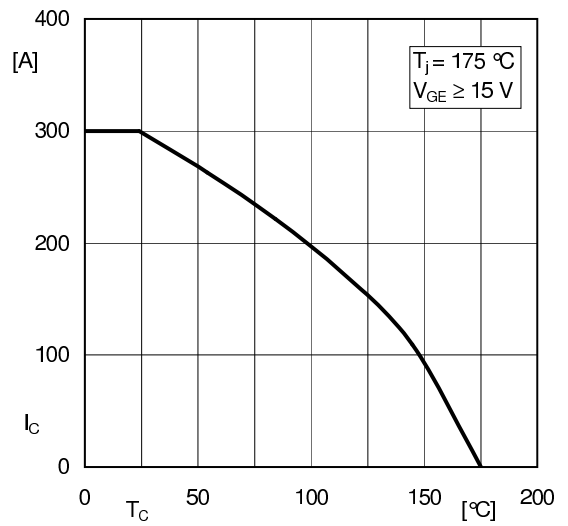


Fig. 2: Rated current vs. temperature $I_C = f(T_C)$

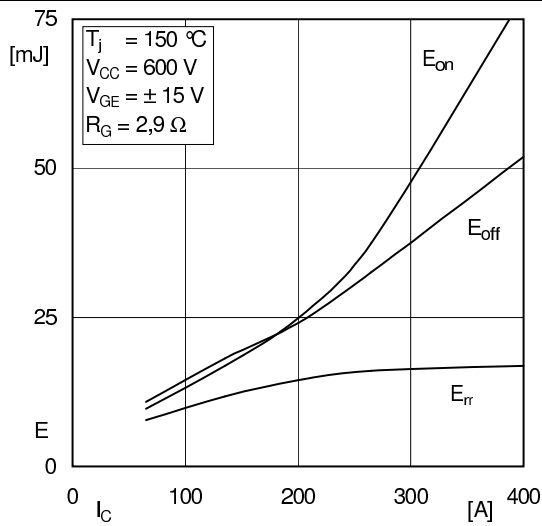


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

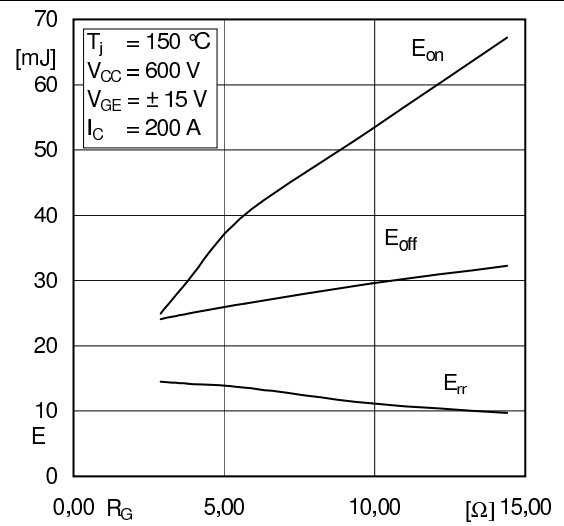


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

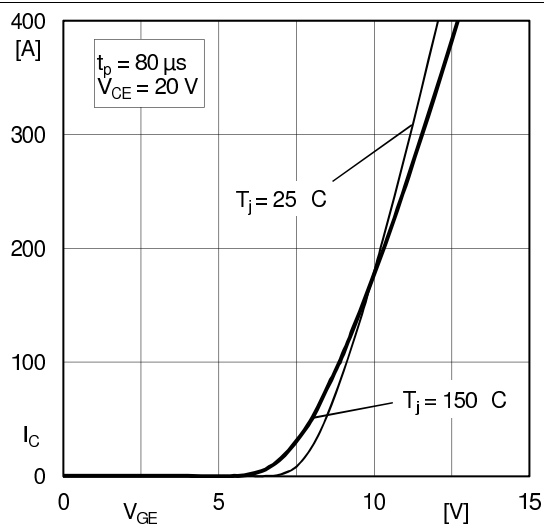


Fig. 5: Typ. transfer characteristic

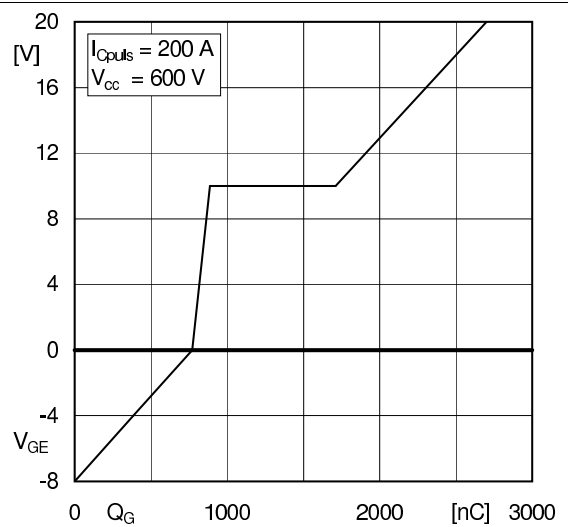
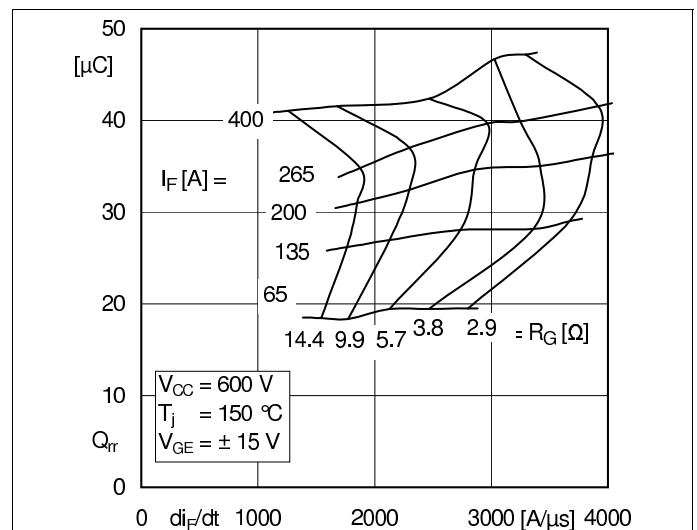
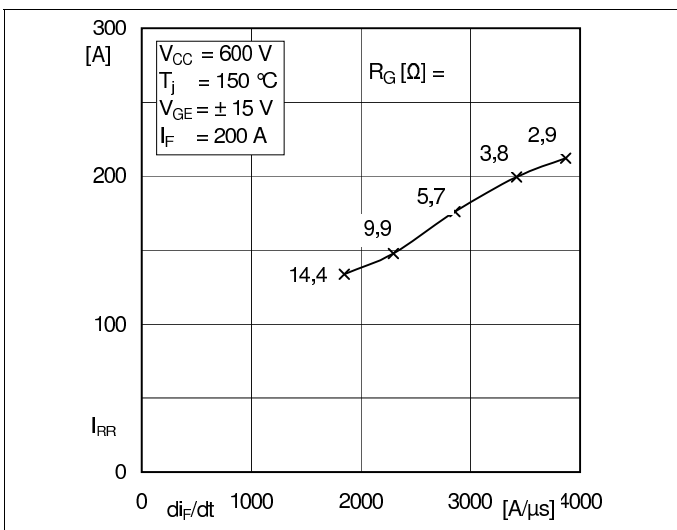
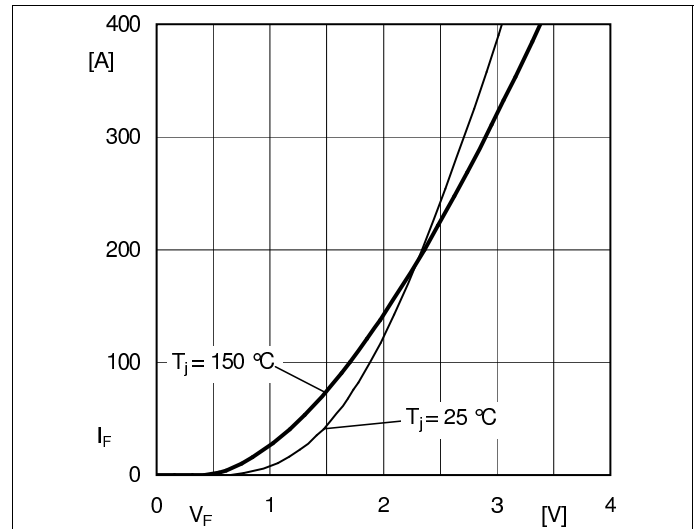
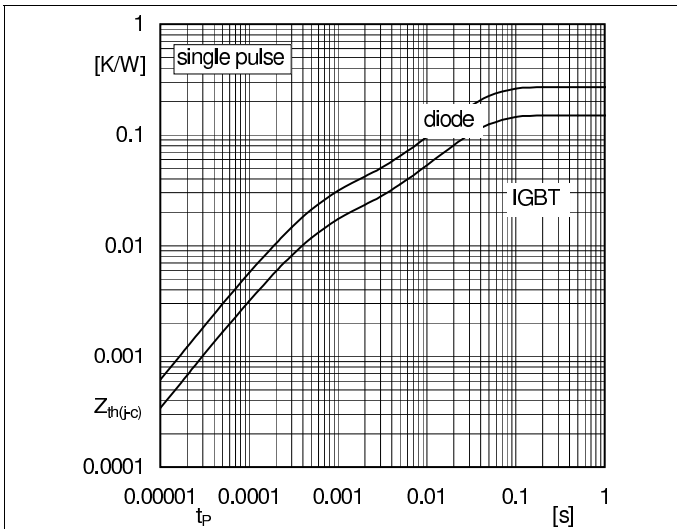
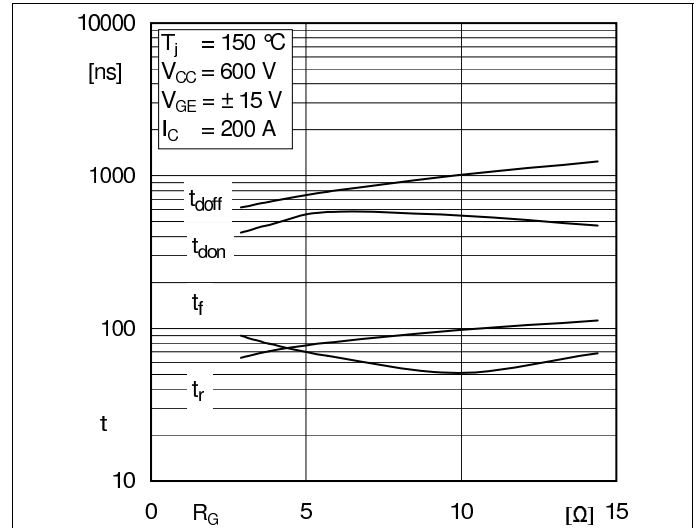
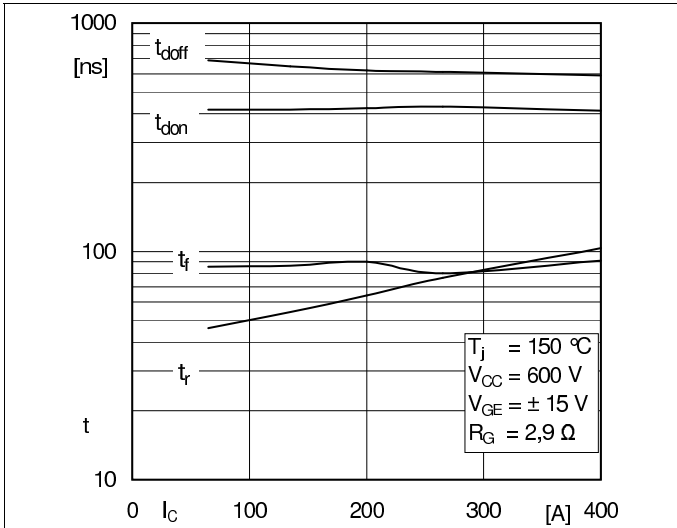


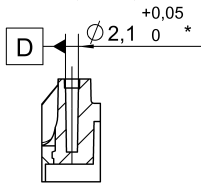
Fig. 6: Typ. gate charge characteristic



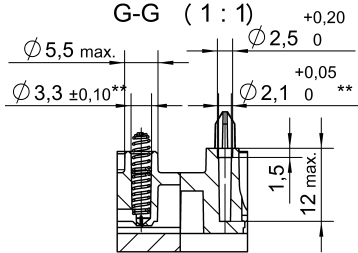
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Case: SEMiX 2s

screw duct
(left top) :
F-F (1:1)

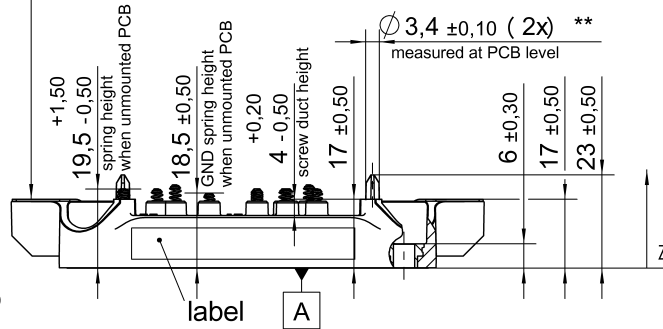


screw duct (4x)
spring duct (12x) :
G-G (1:1)



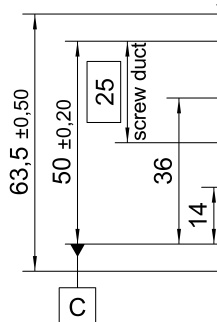
	0,3	connector 1-2 / 3-4
	0,2	each connector A

general tolerance:
ISO 2768-mK
ISO 8015

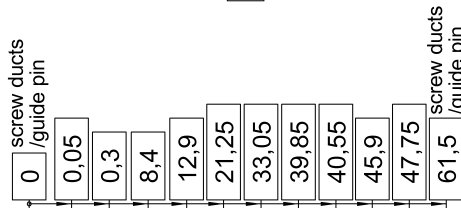
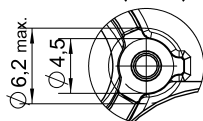


All measures in Z-direction
valid when mounted to heat sink

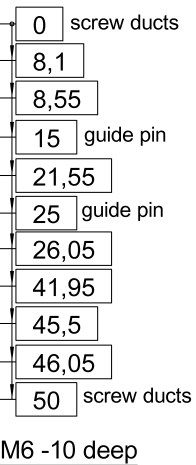
marking of terminals



screw duct
top view (4x) :
J (2:1)



marking of terminals



*screw duct left / top with

\oplus	ϕ 0,2	A	B	C
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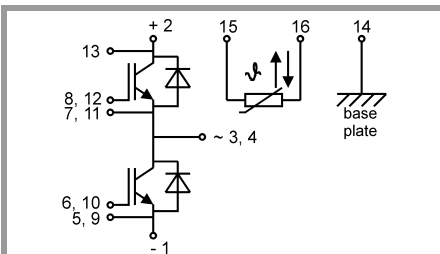
**screw ducts / guide pins / spring ducts with

\oplus	ϕ 0,2	A	D	C
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Rules for the contact PCB:

- holes guidepins = ϕ 4 ± 0,1 / position tolerance ± 0,1
- holes for screws = ϕ 2,9 ± 0,1 / position tolerance ± 0,1
- spring contact pad = ϕ 3,6 ± 0,1 / position tolerance ± 0,1

SEMiX 2s



spring configuration

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our staff.